PATENT COOPERATION TREATY

PCT

INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

(Chapter I of the Patent Cooperation Treaty)

(PCT Rulc 44bis)

Applicant's or agent's file reference P2003,0487WO	FOR FURTHER ACTION	See item 4 below Priority date (day/month/year) 31 July 2003 (31.07.2003)		
International application No. PCT/DE2004/001594 /	International filing date (day/month/year) 22 July 2004 (22.07.2004)			
International Patent Classification (8th edition unless older edition indicated) See relevant information in Form PCT/ISA/237				
Applicant OSRAM OPTO SEMICONDUCTORS GMBH 📝				

1.	This international preliminary report on patentability (Chapter I) is issued by the International Bureau on behalf of the International Searching Authority under Rule 44 bis. 1(a).				
2.	This REPORT consists of a total of 9 sheets, including this cover sheet. In the attached sheets, any reference to the written opinion of the International Searching Authority should be read as a reference to the international preliminary report on patentability (Chapter I) instead.				
3.	This report contains indications relating to the following items:				
	Box No. I	Basis of the report			
	Box No. II	Priority			
	Box No. III	Non-establishment of opinion with regard to novelty, inventive step and industrial applicability			
	Box No. IV	Lack of unity of invention			
	Box No. V	Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement			
	Box No. VI	Certain documents cited			
	Box No. VII	Certain defects in the international application			
	Box No. VIII	Certain observations on the international application			
4.	The International Bureau will not, except where the applican date (Rule 44bis .2).	communicate this report to designated Offices in accordance with Rules 44bis.3(c) and 93bis.1 but it makes an express request under Article 23(2), before the expiration of 30 months from the priority			

	Date of issuance of this report 29 May 2006 (29.05.2006)
The International Bureau of WIPO 34, chemin des Colombettes 1211 Geneva 20, Switzerland	Authorized officer Agnes Wittmann-Regis
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Form PCT/IB/373 (January 2004)

PATENT COOPERATION TREATY

EPPING HERMANN FISCHER

From the INTERNATIONA	L SEARCHING AUTHO	RITY		San	
ľo:				PCT Calion	
			WR INTERNATI	ITTEN OPINION OF THE ONAL SEARCHING AUTHORITY	
				(PCT Rule 43bis.1)	
			Date of mailing (day/month/year)		
			FOR FURTHER ACTION		
1	ent's tile reference		FORFURINERA	See paragraph 2 below	
P2003,0		International filing date	(dowlwouth/year)	Priority date (dawmonth/year)	
PCT/DE2	004/001594	22.07.2004	(m.y.moians veor)	31.07.2003	
International Pate	ent Classification (IPC) or b	ooth national classification as	nd IPC		
	-	relating to the following iten	n &		
Box No. III Non-establishment of opinion with Box No. IV Lack of unity of invention Reasoned statement under Rule 43			egard to novelty, inven	tive step and industrial applicability	
			is.1(a)(i) with regard to ions supporting such sta	novelty, inventive step or industrial	
		documents cited			
	Box No. VII Certain	defects in the international	application		
	Box No. VIII Certain	observations on the internat	ional application		
2. FURTHERACTION If a demand for international preliminary examination is made, this opinion will be considered to be a written opinion of International Preliminary Examining Authority ("IPEA") except that this does not apply where the applicant chooses an Authority of that this one to be the IPEA and the chosen IPEA has notified the International Bureau under Rule 66.1bis(b) that written opinions this International Searching Authority will not be so considered.					
If this opinion is, as provided above, considered to be a written opinion of the IPEA, the applicant is invited to submit to the IPEA written reply together, where appropriate, with amendments, before the expiration of 3 months from the date of mailing of For PCT/ISA/220 or before the expiration of 22 months from the priority date, whichever expires later.					
For further options, see Form PCT/ISA/220. 3. For further details, see notes to Form PCT/ISA/220.					
3. For	to the delais, see holes to				
Name and ma	iling address of the ISA/EP	· · · · · · · · · · · · · · · · · · ·	Authorized office		
			Telephone No.		

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P.	. No. 7	Pasic of this aninion
1503	No. I	Basis of this opinion
1.	With filed.	regard to the language, this opinion has been established on the basis of the international application in the language in which it was unless otherwise indicated under this item.
		This opinion has been established on the basis of a translation from the original language into the following language
		, which is the language of a translation furnished for the purposes of international search (under
	_	Rule 12.3 and 23.1(b)).
2.	With	n regard to any nucleotide and/or amino acid sequence disclosed in the international application and necessary to the claimed intion, this opinion has been established on the basis of:
	2	type of material
		a sequence listing
		table(a) related to the sequence listing
	b.	format of material
		in written formst
		in computer readable form
	c,	time of filing/furnishing
		contained in the international application as filed.
		filed together with the international application in computer readable form.
		furnished subsequently to this Authority for the purposes of search.
3.		In addition, in the case that more than one version or copy of a sequence listing and/or table(s) relating thereto has been filed or furnished, the required statements that the information in the subsequent or additional copies is identical to that in the application as filed or does not go beyond the application as filed, as appropriate, were furnished.
4	. Λ ά	ditional comments:
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Во	No.V	Ressoned statement u	nder Rul ions sup	le 43bis.1(a)(i) with regord to novelty, inventive step or industrial applicability; porting such statement	
1.	Statement				
	Novelty (N	I)	Claims	1-17	YES
		•	Claims	18	NO
	Inventive :	acb (I2)	Claims	1-17	YES
			Claims	18	МО
	Industrial	applicability (IA)	Claims	1-18	YES
		•	Claims		NO

2. Citations and explanations:

I. Claims 1 to 17:

- 1. The article "Selective area deposited blue GaN-InGaN multiple-quantum well light emitting diodes over silicon substrates" by J.W. Yang et al., which was published in Applied Physics Letters, Vol. 76, No. 3 (17 January 2000), pages 273-275, XP-12025677, and is referred to as D1 in the procedure hereinafter, describes (see page 273, right-hand column, 2nd paragraph, to page 274, left-hand column, 2nd paragraph, and figure 1) a method for the production of a plurality of optoelectronic semiconductor chips respectively comprising a plurality of structural elements respectively having at least one semiconductor layer, the method comprising the following method steps:
 - provision of a chip composite base having a substrate (n⁺ Si substrate) and also a growth surface (AlN buffer layer);
 - formation of a mask material layer on the growth surface, with a plurality of windows, a mask material being chosen in such a way that a semiconductor material of the semiconductor

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Hox No. V Reasoned statement under Rule 43bis. 1(s)(i) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

layer, which is grown in a later method step, cannot grow on said material or can grow in a substantially worse manner in comparison with the growth surface; and

- essentially simultaneous growth of semiconductor layers on regions of the growth surface that lie within the windows.
- 2. The subject-matter of claim 1 differs from this by virtue of the fact that the mask material layer grows incompletely and the windows are formed thereby, and by virtue of the fact that the chip composite base with the applied material is singulated to form semiconductor chips.
- 3. Although not discussed expressly in document D1, it is nevertheless readily clear to a person skilled in the art that a wafer with a plurality of semiconductor components can be singulated if individual components are needed and, by way of example, a display is not intended to be produced. Therefore, this features is to be regarded as implicitly disclosed.
- 4. The windows investigated in document D1 are produced by etching the mask material layer and are therefore also not statistically distributed. Another possibility for forming windows is described in the article "Selective growth of nanocrystalline Si dots using an ultrathin-Si-oxide/oxynitride mask" by N. Miyata et al., which was published in Applied Physics Letters, Vol. 77, No. 11 (11 September

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Box No. V Reasoned statement under Rule 43bis.1(a)(i) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

2000), pages 1620 to 1622, and is referred to as D2 in the procedure hereinafter (see page 1620, left-hand column, 1st paragraph, to page 1621, left-hand column, 2nd paragraph, and figure 1). In this case the windows are produced by means of a focused electron beam, but only after the mask material layer has grown in closed fashion. The document EP-A-O 472 221, which is referred to as D3 in the procedure hereinafter, also uses etching (see column 8, lines 2 to 41, and figures 8A-8F). Documents D2 and D3 are concerned, in the same way as D1, with the selective growth of semiconductor material in a window in a mask layer.

- 5. The available prior art does not disclose any method in which the mask layer is applied incompletely in order to obtain windows for selective growth in this way. Therefore, a person skilled in the art would be able to overcome the gap between the teaching of document D1 and the subject-matter of claim 1 only by means of an inventive effort. Claim 1 therefore appears to meet the requirements of PCT Article 33(2) and (3).
- 6. Claims 2 to 17 are dependent on claim 1, that is to say that they contain all the features of claim 1. Since claim 1 appears to meet the requirements of PCT Article 33(2) and (3), this is evidently the case for claims 2 to 17 as well.

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WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY

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Box No. V

Reasoned statement under Rule 43bis. (a)(i) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement

II. Claim 18:

semiconductor chip with a light-emitting component. Since the chip has been singulated, it is no longer possible to draw a conclusion about the statistical distribution of the basic area size, and irregular forms of the basic area are also to be expected in the case of the method according to document D2. The details of the production method can therefore no longer be inferred from the finished semiconductor chip. Since, in the case of etching the windows as well, there will be basic area forms as in the case of incomplete growth of the mask material layer, claim 18 does not appear to meet the requirements of PCT Article 33(2) and (3) (also see notes under Box VIII below).

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Box No. VII Certain defects in the international application

The following defects in the form or contents of the international application have been noted:

- 1. Independent claim 1 has not been drafted in the two-part form defined by PCT Rule 6.3(b). However, in the present case the two-part form would appear to be appropriate. Accordingly, the features known in combination from the prior art (document Dl) should be placed in the preamble (PCT Rule 6.3(b)(i)) and the remaining features in the characterizing part (PCT Rule 6.3(b)(ii)).
- 2. Contrary to PCT Rule 5.1(a)(ii), the description does not cite documents D1 and D2 or indicate the relevant prior art disclosed therein.

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Box No. VIII Certain observations on the international application

The following observations on the clarity of the claims, description, and drawings or on the question whether the claims are fully supported by the description, are made:

1. Claim 18 is directed at an object but describes it with the aid of a method for its production. Such an "product-by-process" claim can be clear within the meaning of PCT Article 6 only when the method features are unambiguously evident from the finished object. This is obviously not the case here.